# MPSW01, MPSW01A

# **One Watt High Current Transistors**

# **NPN Silicon**

#### **Features**

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage  MPSW01  MPSW01A	V <sub>CEO</sub>	30 40	Vdc
Collector - Base Voltage MPSW01 MPSW01A	V <sub>CBO</sub>	40 50	Vdc
Emitter - Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	1000	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.0 8.0	W mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

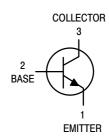
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

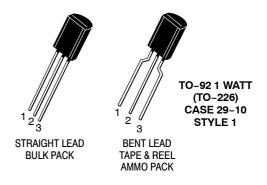
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



# ON Semiconductor®

http://onsemi.com





#### **MARKING DIAGRAM**



x = 01A Devices

A = Assembly Location

= Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MPSW01, MPSW01A

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

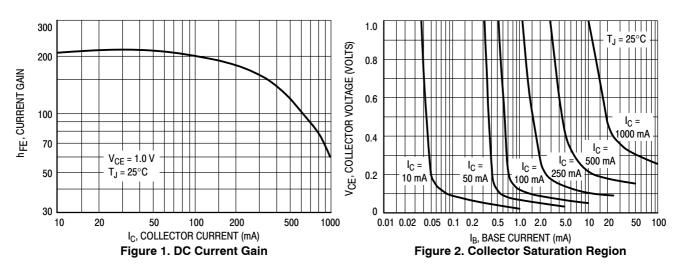
Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS			•	•	•
Collector – Emitter Breakdown Voltage (Note 1) ( $I_C = 10 \text{ mAdc}, I_B = 0$ )	MPSW01 MPSW01A	V <sub>(BR)CEO</sub>	30 40	- -	Vdc
Collector – Base Breakdown Voltage ( $I_C$ = 100 $\mu$ Adc, $I_E$ = 0)	MPSW01 MPSW01A	V <sub>(BR)</sub> CBO	40 50	- -	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 100 \mu Adc$ , $I_C = 0$ )		V <sub>(BR)EBO</sub>	5.0	-	Vdc
Collector Cutoff Current ( $V_{CB} = 30$ Vdc, $I_E = 0$ ) ( $V_{CB} = 40$ Vdc, $I_E = 0$ )	MPSW01 MPSW01A	I <sub>CBO</sub>	- -	0.1 0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	0.1	μAdc
ON CHARACTERISTICS (Note 1)					_
DC Current Gain		h <sub>FE</sub>	55 60 50	- - -	_
Collector – Emitter Saturation Voltage ( $I_C = 1000 \text{ mAdc}$ , $I_B = 100 \text{ mAdc}$	)	V <sub>CE(sat)</sub>	-	0.5	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 1000 mAdc, V <sub>CE</sub> = 1.0 Vdc)		V <sub>BE(on)</sub>	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product ( $I_C = 50$ mAdc, $V_{CE} = 10$ Vdc, $f = 10$	20 MHz)	f <sub>T</sub>	50	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>obo</sub>	-	20	pF

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu\text{s},$  Duty  $\overline{\text{Cycle}}$   $\leq$  2.0%.

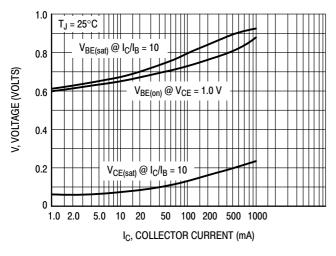
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPSW01	TO-92	5000 Units / Bulk
MPSW01G	TO-92 (Pb-Free)	5000 Units / Bulk
MPSW01AG	TO-92 (Pb-Free)	5000 Units / Bulk
MPSW01ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSW01ARLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



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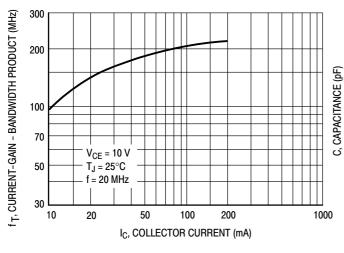
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Figure 3. "ON" Voltages

**Figure 4. Temperature Coefficient** 



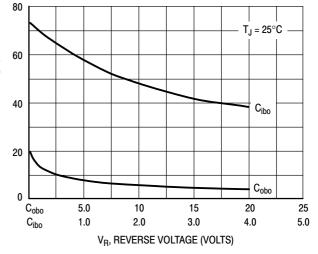


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

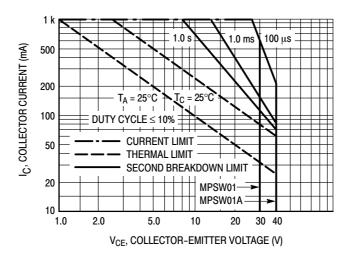
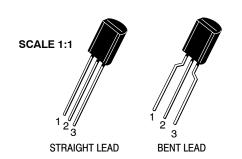


Figure 7. Active Region — Safe Operating Area

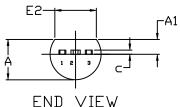


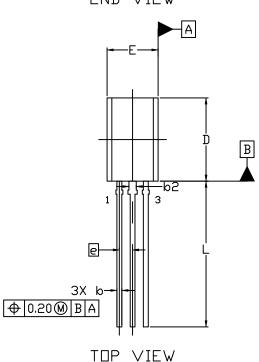


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**DATE 05 MAR 2021** 

## STRAIGHT LEAD





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
- 4. DIMENSION 6 AND 62 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION 62 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

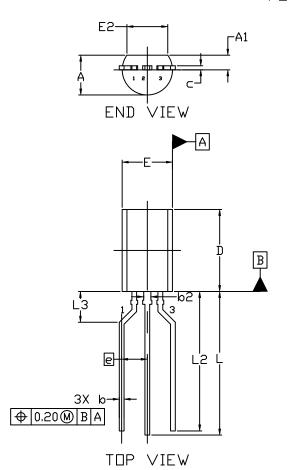
	MILLIMETERS						
DIM	MIN.	N□M.	MAX.				
Α	3.75	3.90	4.05				
A1	1.28	1.43	1.58				
b	0.38	0.465	0.55				
b2	0.62	0.70	0.78				
c	0.35	0.40	0.45				
D	7.85	8.00	8.15				
E	4.75	4.90	5.05				
E2	3.90						
е	1.27 BSC						
L	13.80	14.00	14.20				

## **STYLES AND MARKING ON PAGE 3**

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# FORMED LEAD



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
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e		2.50 BSC					
L	13.80	14.00	14.20				
L2	13.20	13.60	14.00				
L3	3.00 REF						

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# TO-92 (TO-226) 1 WATT

CASE 29-10 ISSUE D

### **DATE 05 MAR 2021**

2.	EMITTER BASE COLLECTOR		BASE EMITTER COLLECTOR		ANODE ANODE CATHODE		CATHODE CATHODE ANODE		DRAIN SOURCE GATE
	GATE	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN	STYLE 8: PIN 1. 2. 3.	DRAIN GATE	2.	BASE 1	2.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE	PIN 1. 2.	MAIN TERMINAL 1	PIN 1. 2.	GATE	2.	EMITTER	2.	ANODE 1 CATHODE ANODE 2
2.	ANODE GATE CATHODE	STYLE 17: PIN 1. 2. 3.	COLLECTOR BASE EMITTER		ANODE CATHODE NOT CONNECTED		GATE ANODE CATHODE	2.	NOT CONNECTED CATHODE ANODE
2.		2.	SOURCE GATE DRAIN		GATE SOURCE DRAIN	PIN 1. 2.	EMITTER	2.	MT 1
	V <sub>CC</sub>			PIN 1. 2.		PIN 1. 2.	NOT CONNECTED ANODE CATHODE		
	GATE	STYLE 32: PIN 1. 2. 3.	BASE COLLECTOR EMITTER	2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT GROUND LOGIC		

# GENERIC MARKING DIAGRAM\*



XXXX = Specific Device Code

A = Assembly Location

L = Wafer Lot Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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